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2N5629 2N5630 NPN
 2N6029 2N6030 PNP

COMPLEMENTARY SILICON POWER
 TRANSISTORS

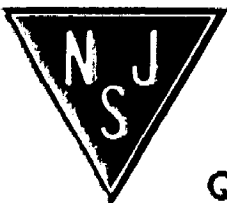
JEDEC TO-3 CASE

MAXIMUM RATINGS ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	2N5629 2N6029	2N5630 2N6030	UNIT
Collector-Emitter Voltage	V_{CEO}	100	120	V
Collector-Base Voltage	V_{CBO}	100	120	V
Emitter-Base Voltage	V_{EBO}		7.0	V
Collector Current	I_C		16	A
Collector Current-PEAK	I_{CM}		20	A
Base Current	I_B		5.0	A
Power Dissipation	P_D		200	W
Operating and Storage Junction Temperature	T_J, T_{STG}	-60 to +200		$^\circ\text{C}$
Thermal Resistance	θ_{JC}	0.875		$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
I_{CEV}	$V_{CE}=\text{Rated } V_{CB}, V_{EB}(\text{OFF})=1.5\text{V}$		1.0	mA
I_{CEV}	$V_{CE}=\text{Rated } V_{CB}, V_{EB}(\text{OFF})=1.5\text{V}, T_C=150^\circ\text{C}$		5.0	mA
I_{CEO}	$V_{CE}=\frac{1}{2} \text{ Rated } V_{CEO}$		1.0	mA
I_{CBO}	$V_{CB}=\text{Rated } V_{CBO}$		1.0	mA
I_{EBO}	$V_{BE}=7.0\text{V}$		1.0	mA
BV_{CEO}	$I_C=200\text{mA}$ (2N5629, 2N6029)	100		V
BV_{CEO}	$I_C=200\text{mA}$ (2N5630, 2N6030)	120		V
$V_{CE}(\text{SAT})$	$I_C=10\text{A}, I_B=1.0\text{A}$		1.0	V
$V_{CE}(\text{SAT})$	$I_C=16\text{A}, I_B=4.0\text{A}$		2.0	V
$V_{BE}(\text{SAT})$	$I_C=10\text{A}, I_B=1.0\text{A}$		1.8	V
$V_{BE}(\text{ON})$	$V_{CE}=2.0\text{V}, I_C=8.0\text{A}$		1.5	V
h_{FE}	$V_{CE}=2.0\text{V}, I_C=8.0\text{A}$ (2N5629, 2N6029)	25	100	
h_{FE}	$V_{CE}=2.0\text{V}, I_C=8.0\text{A}$ (2N5630, 2N6030)	20	80	
h_{FE}	$V_{CE}=2.0\text{V}, I_C=16\text{A}$	4.0	-	
h_{fe}	$V_{CE}=10\text{V}, I_C=4.0\text{A}, f=10\text{kHz}$	15	-	
f_T	$V_{CE}=20\text{V}, I_C=1.0\text{A}, f=0.5\text{MHz}$	1.0	-	MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=0.1\text{MHz}$		500	pF
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=0.1\text{MHz}$		1000	pF



NJ Semi-Conductors reserves the right to change test conditions, parameters limits and package dimensions without notice information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors